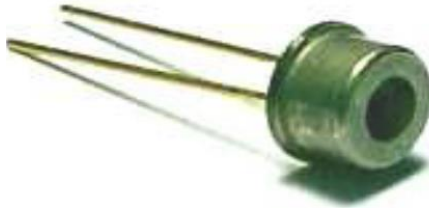




GFUV-T10GD-L

Far UV Photodiode Large Area



Features

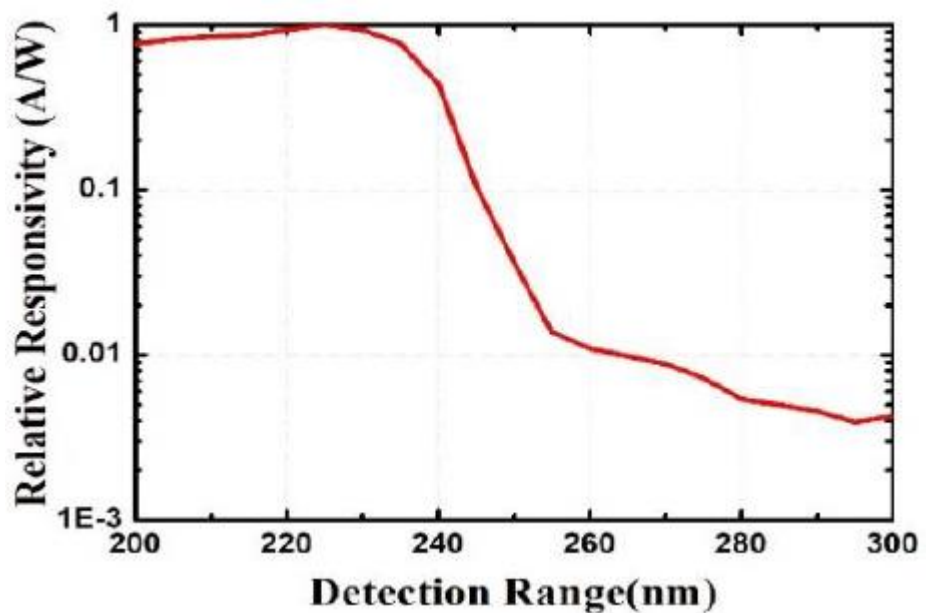
- AlGaN based material
- Schottky Type Photodiode
- Photovoltaic Mode Operation
- Good Solar Blindness

Applications

- Far UV Monitoring
- Eximer Lamp Monitoring

Spectral Response Curve

Spectral Response Curve, relative



Measured with

172nm Peak Lamp Spectrum	VUV Lamp	rel Level = 0,05
222nm Peak Lamp Spectrum	FUV-Lamp	rel Level = 1

OEC



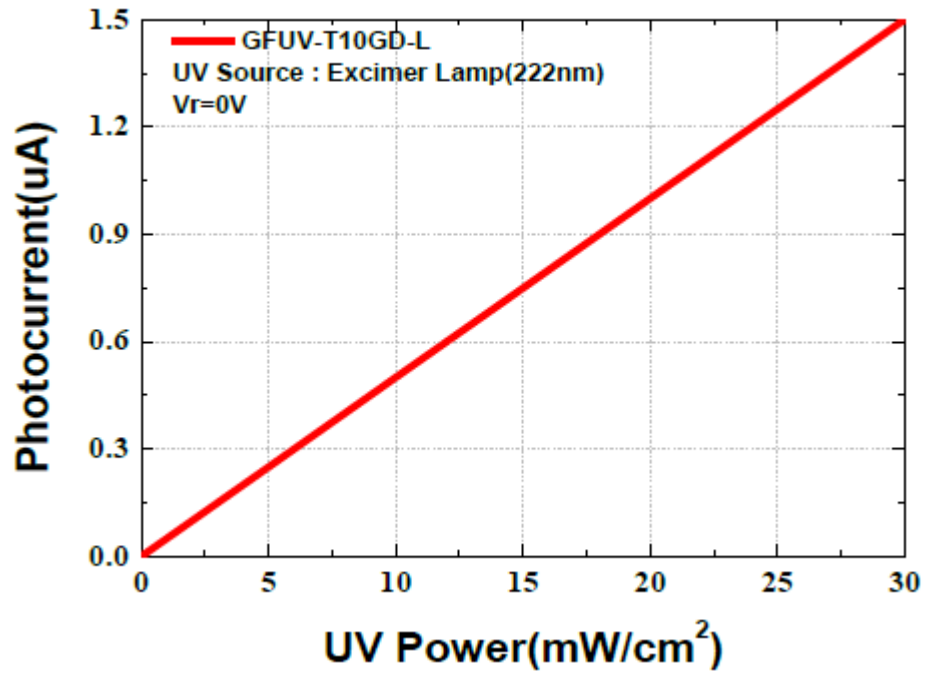
Opto-Electronic
Components



OEC
YOUR PARTNER

Stand 02.07.2018

Photocurrent along UV Power



CAUTION

ESD can damage the device hence, please, avoid ESD.
Insulate the cap of TO-CAN or it can cause malfunction of the device.



Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit	Remark
Storage Temperature	T_{st}	-40	90	$^{\circ}C$	
Operating Temperature	T_{op}	-30	85	$^{\circ}C$	
Reverse Voltage	$V_{r, max.}$		2	V	
Forward Current	$I_{f, max.}$		1	mA	
Optical Source Power Range	P_{opt}	0.1m	100m	W/cm ²	Excimer Lamp
Soldering Temperature	T_{sol}		260	$^{\circ}C$	within 10 sec.

※Notice: apply to us in the case that Optical Source Power is over 100,000 μ W/cm².

Characteristics (at 25 $^{\circ}C$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Dark Current	I_d			100	pA	$V_r = 1 V$
Photo Current	I_{ph}	45	50	55	nA	222nm peak FUV Lamp, 1 mW/cm ²
		2.12	2.35	2.58	nA	172nm peak VUV Lamp, 1 mW/cm ²
Spectral Detection range	λ			245	nm	
Active area			1.536		mm ²	



Package

Stand 02.07.2018

Outline Diagrams and Dimensions

